







SN54HC540, SN74HC540

## ZHCSPQ5F - MARCH 1984 - REVISED JULY 2022

# SNx4HC540 具有三态输出的八路缓冲器和线路驱动器

## 1 特性

- 2V 至 6V 的宽工作电压范围
- 高电流三态输出直接驱动总线或驱动最多 15 个 LSTTL 负载
- 低功耗,I<sub>CC</sub> 最大值为 80µA
- t<sub>pd</sub> 典型值 = 8ns
- 电压为 5V 时,输出驱动为 ±6mA
- 低输出电流,最大值 1µA
- 数据直通式引脚排列(所有输入均在输出对侧)

## 2 说明

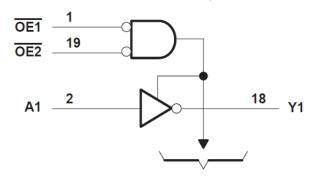
这些八路缓冲器和线路驱动器具有常见 'HC240 系列器 件的性能,并提供封装两侧输入和输出的引脚排列。这 种布置非常有助于印刷电路板布局布线。

三态控制栅极为 2 输入或非门。如果任一输出使能端 (OE1 或 OE2)输入为高电平,则所有八路输出均处 于高阻抗状态。'HC540 器件在输出端提供反相数据。

#### 器件信息

器件型号	封装 <sup>(1)</sup>	封装尺寸 ( 标称值 )
SN54HC540J	CDIP (20)	26.92mm × 6.92mm
SN74HC540DW	SOIC (20)	12.80mm × 7.50mm
SN74HC540N	PDIP (20)	25.40mm × 6.35mm
SN74HC540NSR	SO (20)	15.00mm × 5.30mm
SN74HC540PW	TSSOP (20)	6.50mm × 4.40mm

如需了解所有可用封装,请参阅数据表末尾的可订购产品附



To Seven Other Channels

功能方框图

English Data Sheet: SCLS007



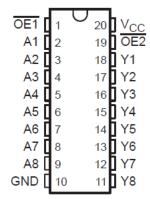
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3 Revision History 注:以前版本的页码可能与当前版本的页码不同		
Changes from Revision E (January 2022) to Revision	ո F (July 2022) Pa	age
· Junction-to-ambient thermal resistance values increa	sed. DW was 58 is now 109.1, N was 69 is now 84.6,	
NS was 60 is now 113.4, PW was 83 is now 131.8		4

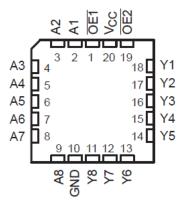
Changes from Revision D (August 2003) to Revision E (January 2022)



## **4 Pin Configuration and Functions**



J, DW, N, NS, PW package 20-Pin CDIP, SOIC, PDIP, SO, TSSOP Top View



FK Package 20-Pin CDIP Top View



## **5 Specifications**

## **5.1 Absolute Maximum Ratings**

overoperating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0 \text{ or } V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±35	mA
	Continuous current through V <sub>CC</sub> or GND	·	-	±70	mA
TJ	Junction temperature		-	150	°C
T <sub>stg</sub>	Storage temperature range	<b>–</b> 65	150	°C	
	Lead temperature (Soldering 10s) (SOIC -		300	°C	

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is notimplied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## **5.2 Recommended Operating Conditions**(1)

			SN	54HC540		SN	74HC540		UNIT	
			MIN	NOM	MAX	MIN	NOM	MAX	UNII	
V <sub>CC</sub>	Supply voltage		2	5	6	2	5	6	V	
		V <sub>CC</sub> = 2 V	1.5			1.5				
V <sub>IH</sub>	V <sub>IH</sub> High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			3.15			V	
		V <sub>CC</sub> = 6 V	4.2			4.2				
	V <sub>IL</sub> Low-level input voltage	V <sub>CC</sub> = 2 V			0.5			0.5	V	
V <sub>IL</sub>		V <sub>CC</sub> = 4.5 V			1.35			1.35		
		V <sub>CC</sub> = 6 V			1.8			1.8		
VI	Input voltage		0		V <sub>CC</sub>	0		V <sub>CC</sub>	V	
Vo	Output voltage		0		V <sub>CC</sub>	0		$V_{CC}$	V	
		V <sub>CC</sub> = 2 V			1000			1000		
Δt/Δν	Δt/Δv Input transition rise/fall time	V <sub>CC</sub> = 4.5 V			500			500	ns	
		V <sub>CC</sub> = 6 V			400			400		
T <sub>A</sub>	Operating free-air temperature		-55		125	-40		85	°C	

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

#### **5.3 Thermal Information**

			N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC		20 PINS	20 PINS	20 PINS	20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance <sup>(1)</sup>	109.1	84.6	113.4	131.8	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	76	72.5	78.6	72.2	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	77.6	65.3	78.4	82.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	51.5	55.3	47.1	21.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	77.1	65.2	78.1	82.4	°C/W

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<sup>(2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



## 5.3 Thermal Information (continued)

		DW (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC		20 PINS	20 PINS	20 PINS	20 PINS	UNIT
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

#### **5.4 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NDITIONS	V	T <sub>A</sub> = 25°C			SN54HC540		SN74HC540		UNIT
PARAMETER	PARAMETER TEST CONDITIO		V <sub>CC</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
			2 V	1.9	1.998		1.9		1.9		
		I <sub>OH</sub> = -20 μA	4.5 V	4.4	4.499		4.4		4.4		
V <sub>OH</sub>	$V_{OH}$ $V_{I} = V_{IH}$ or $VI_{IL}$		6 V	5.9	5.999		5.9		5.9		V
		I <sub>OH</sub> = −6 mA	4.5 V	3.98	4.3		3.7		3.84		
		I <sub>OH</sub> = −7.8 mA	6 V	5.48	5.8		5.2		5.34		
			2 V		0.002	0.1		0.1		0.1	
		I <sub>OL</sub> = 20 μA	4.5 V		0.001	0.1		0.1		0.1	
V <sub>OL</sub>	$V_I = V_{IH}$ or $V_{IL}$		6 V		0.001	0.1		0.1		0.1	V
		I <sub>OL</sub> = 6 mA	4.5 V		0.17	0.26		0.4		0.33	
		I <sub>OL</sub> = 7.8 mA	6 V		0.15	0.26		0.4		0.33	
II	V <sub>I</sub> = V <sub>CC</sub> or 0		6 V		±0.1	±100		±1000		±1000	nA
I <sub>OZ</sub>	$V_O = V_{CC}$ or 0		6 V		±0.01	±0.5		±10		±5	μΑ
I <sub>CC</sub>	$V_I = V_{CC}$ or 0,	I <sub>O</sub> = 0	6 V			8		160		80	μΑ
Ci			2 V to 6 V		3	10		10		10	pF

## 5.5 Switching Characteristics

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see  $\boxtimes 6-1$ )

PARAMETER	FROM	то	V		= 25°C		SN54HC540	)	SN74HC	540	UNIT
(INPUT)		(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN N	ΙΑΧ	MIN	MAX	UNIT
			2 V		35	100		149		125	
t <sub>pd</sub>	Α	Y	4.5 V		10	20		30		25	ns
			6 V		8	17		25		21	
			2 V		75	150		224		188	
t <sub>en</sub>	ŌĒ	Y	4.5 V		15	30		45		38	ns
			6 V		13	26		38		32	
			2 V		40	150		224		188	
t <sub>dis</sub>	ŌĒ	Y	4.5 V		18	30		45		38	ns
			6 V		17	26		38		32	
			2 V		28	60		90		75	
t <sub>t</sub>		Y	4.5 V		8	12		18		15	ns
			6 V		6	10		15		13	



## **5.6 Switching Characteristics**

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (see 图 6-1)

PARAMETER	FROM	то	V	T <sub>A</sub> =	= 25°C		SN54HC	540	SN74HC540		UNIT	
(INPUT)		(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII	
				2 V		60	150		224		188	
t <sub>pd</sub>	Α	Y	4.5 V		15	30		45		38	ns	
			6 V		13	26		38		32		
	ŌĒ		2 V		100	200		298		250		
t <sub>en</sub>		Y	4.5 V		20	40		60		50	ns	
			6 V		17	34		51		43		
			2 V		45	210		315		265		
t <sub>t</sub>		Y	4.5 V		17	42		63		53	ns	
			6 V		13	36		53		45		

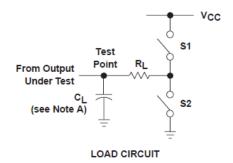
## **5.7 Operating Characteristics**

T<sub>A</sub> = 25°C

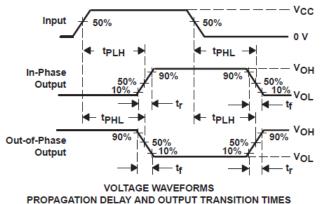
	PARAMETER	TEST CONDITIONS	TYP	UNIT
$C_{pd}$	Power dissipation capacitance per buffer/driver	No load	35	pF

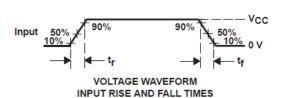


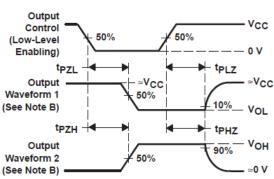
#### **6 Parameter Measurement Information**



PARA	METER	RL	CL	<b>S</b> 1	S2
tPZH		50 pF 1 kΩ or		Open	Closed
ten	t <sub>PZL</sub>	1 K52	150 pF	Closed	Open
tara	t <sub>PHZ</sub>	1 kΩ	50 pF	Open	Closed
<sup>t</sup> dis	tPLZ	1 1132	30 pi	Closed	Open
t <sub>pd</sub> or t <sub>t</sub>		-	50 pF or 150 pF	Open	Open







VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_r = 6$  ns,  $t_f = 6$  ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

图 6-1. Load Circuit and Voltage Waveforms

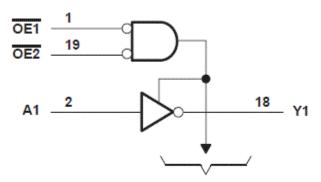
## 7 Detailed Description

### 7.1 Overview

These octal buffers and line drivers feature the performance of the popular 'HC240 series and offer a pinout with inputs and outputs on opposite sides of the package. This arrangement greatly facilitates printed circuit board layout.

The 3-state control gate is a 2-input NOR. If either output-enable ( $\overline{OE1}$  or  $\overline{OE2}$ ) input is high, all eight outputs are in the high-impedance state. The 'HC540 devices provide inverted data at the outputs.

#### 7.2 Functional Block Diagram



To Seven Other Channels

#### 7.3 Device Functional Modes

表 7-1. Function Table (Each Buffer/Driver)

	INPUTS						
OE1	OE2	Α	Y				
L	L	L	Н				
L	L	Н	L				
Н	Х	Х	Z				
X	Н	Х	Z				



### 8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each  $V_{CC}$  terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- $\mu$ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- $\mu$ F and 1- $\mu$ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

### 9 Layout

#### 9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or  $V_{CC}$ , whichever makes more sense for the logic function or is more convenient.

## 10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

#### 10.1 接收文档更新通知

要接收文档更新通知,请导航至 ti.com 上的器件产品文件夹。点击*订阅更新* 进行注册,即可每周接收产品信息更 改摘要。有关更改的详细信息,请查看任何已修订文档中包含的修订历史记录。

### 10.2 支持资源

TI E2E™ 支持论坛是工程师的重要参考资料,可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

链接的内容由各个贡献者"按原样"提供。这些内容并不构成 TI 技术规范,并且不一定反映 TI 的观点;请参阅 TI 的《使用条款》。

#### 10.3 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments. 所有商标均为其各自所有者的财产。

#### 10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 10.5 术语表

#### TI术语表

本术语表列出并解释了术语、首字母缩略词和定义。

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### **PACKAGING INFORMATION**

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
JM38510/65710BRA	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65710BRA
JM38510/65710BRA.A	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65710BRA
M38510/65710BRA	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65710BRA
SN54HC540J	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC540J
SN54HC540J.A	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC540J
SN74HC540DWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540DWR.A	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540N	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC540N
SN74HC540N.A	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC540N
SN74HC540NSR	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540NSR.A	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540PW	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	HC540
SN74HC540PWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540PWR.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540PWRE4	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC540
SN74HC540PWT	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	HC540
SNJ54HC540J	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC540J
SNJ54HC540J.A	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC540J

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

## PACKAGE OPTION ADDENDUM

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(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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#### OTHER QUALIFIED VERSIONS OF SN54HC540, SN74HC540:

Catalog: SN74HC540

Military: SN54HC540

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

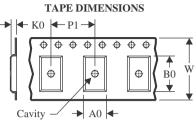
• Military - QML certified for Military and Defense Applications

## **PACKAGE MATERIALS INFORMATION**

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### TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC540DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HC540NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HC540PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74HC540DWR	SOIC	DW	20	2000	356.0	356.0	45.0	
SN74HC540NSR	SOP	NS	20	2000	356.0	356.0	45.0	
SN74HC540PWR	TSSOP	PW	20	2000	353.0	353.0	32.0	

# **PACKAGE MATERIALS INFORMATION**

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### **TUBE**



#### \*All dimensions are nominal

Device	Package Name	Package Type Pins		SPQ	SPQ L (mm)		W (mm) T (μm)	
SN74HC540N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC540N.A	N	PDIP	20	20	506	13.97	11230	4.32

#### 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



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